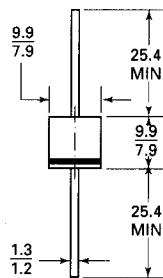


P600A...P600M PLASTIC SILICON RECTIFIERS

FEATURES

- * Low forward voltage
- * High current capability
- * Low leakage current
- * High surge capability
- * Low cost

P600



VOLTAGE RANGE

50 to 1000 Volts

CURRENT

6.0 Amperes

Dimensions in mm

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

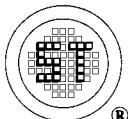
Ratings at 25 °C ambient temperature unless otherwise specified.
Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

	P600A	P600B	P600D	P600G	P600J	P600K	P600M	UNITS
Maximum Recurrent Peak Reverse Voltage	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current .375". 9.5mm Lead Length at T _A = 60 °C					6.0			A
Peak Forward Surge Current 8.3 ms single half sine-wave					350			A
Maximum Forward Voltage at 6.0A Peak				0.95				V
Maximum Reverse Current, Rated DC Blocking Voltage					10			µA
Maximum Full Load Reverse Current, Full Cycle Average. .375", (9.5mm) Lead Length at T _A = 55 °C				100				µA
Typical Junction Capacitance (NOTE 1)				60				pF
Operating and Storage Temperature Range				-65 to + 175				°C

NOTES:

1 Measured at 1.0 MHz and applied reverse voltage of 4.0 V_{DC}.



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ISO 9001-94
Certificate No. QSG-055

P600A...P600M PLASTIC SILICON RECTIFIERS

Fig. 1 — TYPICAL FORWARD CHARACTERISTICS

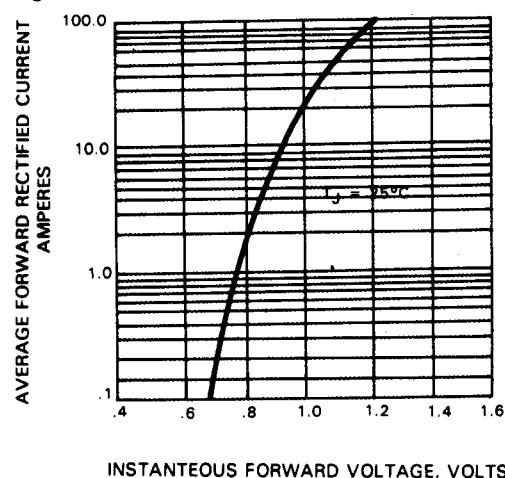


Fig. 2 — PEAK FORWARD SURGE CURRENT

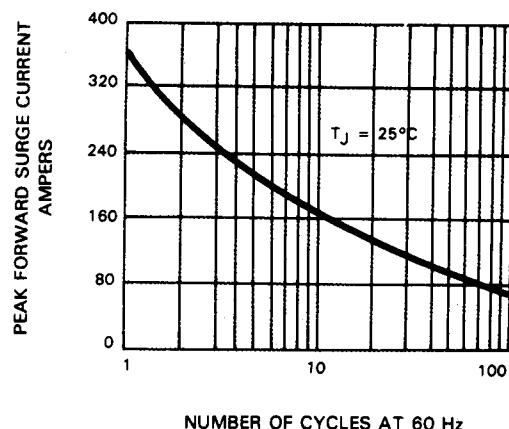


Fig. 3 — FORWARD DURRENT DERATING CURVE

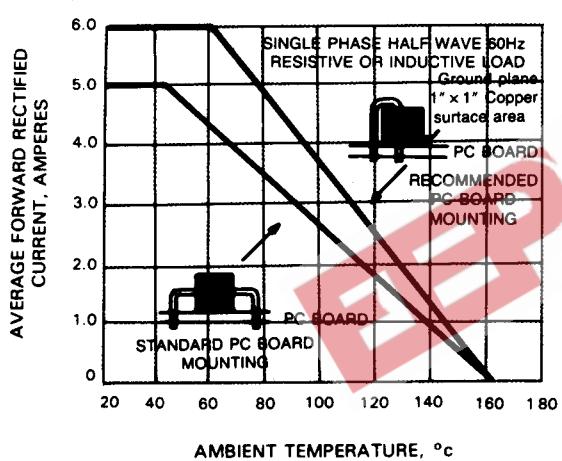
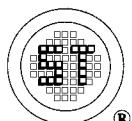
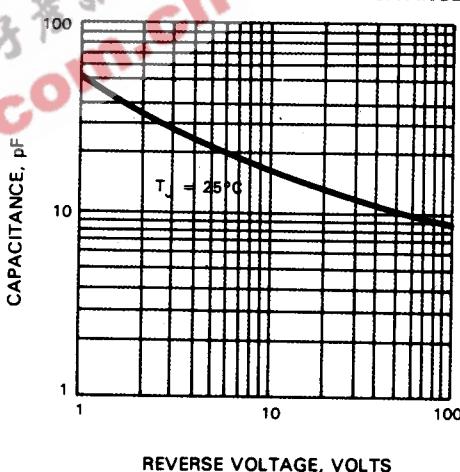


Fig. 4—TYPICAL JUNCTION CAPACITANCE



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